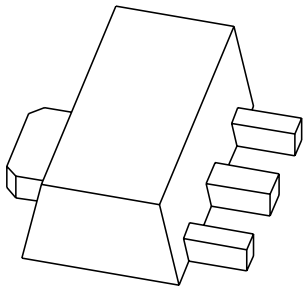
DATA SHEET



BCV29; BCV49
NPN Darlington transistors

Product specification
Supersedes data of 1997 Apr 21

1999 Apr 08

Philips
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NPN Darlington transistors BCV29; BCV49

FEATURES

- High current (max. 500 mA)
- Low voltage (max. 60 V)
- High DC current gain (min. 20000).

APPLICATIONS

- Preamplifier input applications.

DESCRIPTION

NPN small-signal Darlington transistor in a surface mount SOT89 plastic package. PNP complements: BCV28 and BCV48.

MARKING

TYPE NUMBER	MARKING CODE
BCV29	EF
BCV49	EG

PINNING

PIN	DESCRIPTION
1	emitter
2	collector
3	base

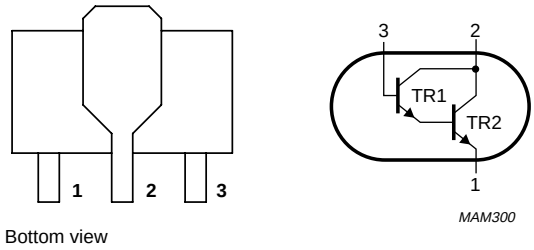


Fig.1 Simplified outline (SOT89) and symbol.

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V_{CBO}	collector-base voltage	open emitter			
	BCV29		–	40	V
	BCV49		–	80	V
V_{CES}	collector-emitter voltage	V_{BE} = 0			
	BCV29		–	30	V
	BCV49		–	60	V
V_{EBO}	emitter-base voltage	open collector	–	10	V
I_C	collector current (DC)		–	500	mA
I_{CM}	peak collector current		–	1	A
I_{BM}	peak base current		–	200	mA
P_{tot}	total power dissipation	$T_{amb} \leq 25$ °C; note 1	–	1.3	W
T_{stg}	storage temperature		–65	+150	°C
T_j	junction temperature		–	150	°C
T_{amb}	operating ambient temperature		–65	+150	°C

Note

1. Device mounted on a printed-circuit board, single-sided copper, tinplated, mounting pad for collector 1 cm^2. For other mounting conditions, see *"Thermal considerations for SOT89 in the General Part of associated Handbook".*

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
$R_{th\ j\text{-}a}$	thermal resistance from junction to ambient	note 1	96	K/W
$R_{th\ j\text{-}s}$	thermal resistance from junction to soldering point		16	K/W

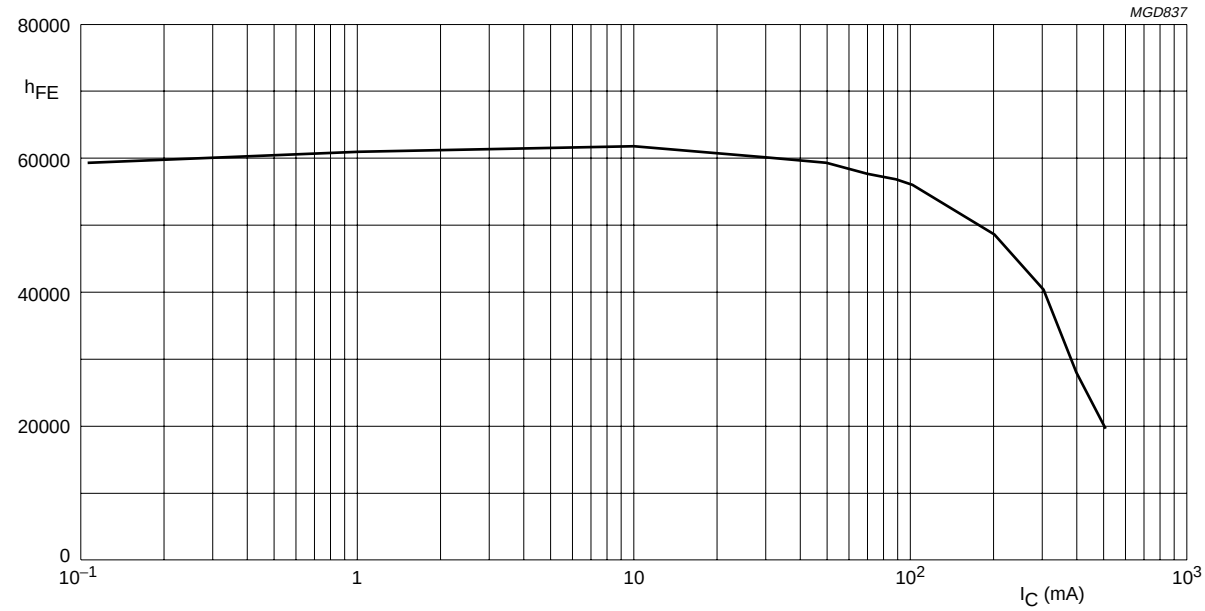
Note

1. Device mounted on a printed-circuit board, single-sided copper, tinplated, mounting pad for collector 1 cm^2.
   For other mounting conditions, see *"Thermal considerations for SOT89 in the General Part of associated Handbook".*

CHARACTERISTICS

T_{amb} = 25 °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I_{CBO}	collector cut-off current					
	BCV29	I_E = 0; V_{CB} = 30 V	–	–	100	nA
	BCV49	I_E = 0; V_{CB} = 60 V	–	–	100	nA
I_{EBO}	emitter cut-off current	I_C = 0; V_{EB} = 10 V	–	–	100	nA
h_{FE}	DC current gain	V_{CE} = 5 V; see Fig.2				
	BCV29	I_C = 1 mA	4000	–	–	
		I_C = 10 mA	10000	–	–	
		I_C = 100 mA	20000	–	–	
		I_C = 500 mA	4000	–	–	
	DC current gain	V_{CE} = 5 V; see Fig.2				
	BCV49	I_C = 1 mA	2000	–	–	
		I_C = 10 mA	4000	–	–	
		I_C = 100 mA	10000	–	–	
		I_C = 500 mA	2000	–	–	
V_{CEsat}	collector-emitter saturation voltage	I_C = 100 mA; I_B = 0.1 mA	–	–	1	V
V_{BEsat}	base-emitter saturation voltage	I_C = 100 mA; I_B = 0.1 mA	–	–	1.5	V
V_{BEon}	base-emitter on-state voltage	I_C = 10 mA; V_{CE} = 5 V	–	–	1.4	V
f_T	transition frequency	I_C = 30 mA; V_{CE} = 5 V; f = 100 MHz	–	220	–	MHz

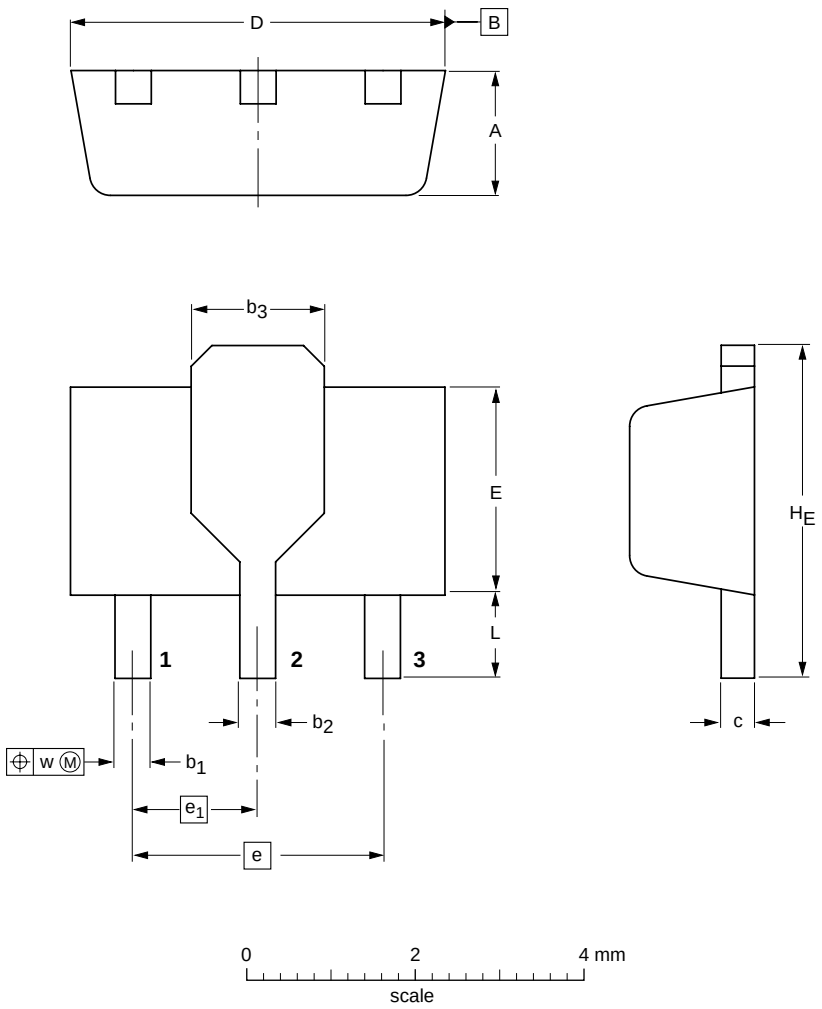


V_{CE} = 2 V.

Fig.2 DC current gain; typical values.

PACKAGE OUTLINE

Plastic surface mounted package; collector pad for good heat transfer; 3 leads **SOT89**



DIMENSIONS (mm are the original dimensions)

UNIT	A	b_1	b_2	b_3	c	D	E	e	e_1	H_E	L min.	w
mm	1.6 1.4	0.48 0.35	0.53 0.40	1.8 1.4	0.44 0.37	4.6 4.4	2.6 2.4	3.0	1.5	4.25 3.75	0.8	0.13

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	EIAJ			
SOT89						97-02-28

DEFINITIONS

Data Sheet Status	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
Limiting values	
Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.	
Application information	
Where application information is given, it is advisory and does not form part of the specification.	

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